Power Over Ethernet 802.3af/at PD Controller

The PD70101 and PD70201 are integrated Powered Device Interface and PWM controllers for a DC-DC converter used in IEEE802.3af and IEEE802.3at applications. The PD70101 can be used for IEEE802.3af or IEEE802.3at Type 1 applications, while the PD70201 can also be used in IEEE802.3at Type 2 applications.

A single PD70201 can be used in 4-pair applications which consumes up to 47.7W.

These devices have a number of features designed to improve efficiency and reliability:

Detection and Classification: The front end interface includes detection and classification circuitry. The detection signature resistor is disconnected upon completion of the detection phase. The system then begins the classification phase. Classification can be configured for Classes 0 to 4 via an external resistor. The PD70201 includes a two-events classification identification circuit which generates a flag to inform the PD application whether the Power Source Equipment (PSE) is Type 1 or Type 2.

Capacitor: A current limited internal MOSFET switch charges the input capacitor of the DC-DC converter. This capacitor is discharged in a timely manner when the input power is removed.

Gate drivers: The PWM DC-DC controller has two built-in gate drivers designed to swing between VCC and GND. These 2 out-of-phase driver stages can be configured for synchronous rectification or active clamp.

Peak current mode control: The DC-DC converter employs peak current mode control for better line and load step response. The switching frequency can be set from 100kHz to 500kHz, enabling a size and efficiency trade off.

Maximum duty cycle is limited to 50% to reduce the power MOSFET switch voltage to two times the input voltage; a 150V rated MOSFET can be used for the primary side switch. The secondary synchronous MOSFET voltage rating depends on the output voltage and can be higher or lower than the primary side MOSFET switch.

Soft-start circuit: The devices include a soft-start circuit to control the output voltage rise time (user settable) at start up, and to limit the inrush current. An integrated startup bias circuit powers the DC-DC controller, until the device starts up by the voltage generated by the bootstrap circuit.

Low Voltage Protection Warning and Monitoring: Dual Under Voltage Lock Out (UVLO), which monitors both the PoE Port Input Voltage and VCC, ensures reliable operation during any system disturbances. The PoE port UVLO has a programmable threshold and hysteresis to enable tailoring to the desired turn on and turn off voltage.

An internal current sense amplifier with a Kelvin connection allows the use of an extremely low resistor to measure the current sense threshold voltage (200 mV) which optimizes efficiency.

Low Power Mode operation is provided to improve efficiency under light loads such as when the PD is in standby. The user can define at what power level the unit enters low power mode by means of a single resistor value.

Features

- IEEE802.3af and IEEE802.3at Compliant
- Support for 4-pair Applications of up to 47.7W With a Single IC
- Two-events Classification Identification With a Level Signal Indicating Type 1 or Type 2 PSE
- Less Than 10 µA (typical) Offset Current During Detection
- Signature Resistor is Disconnected upon Detection
- Programmable Classification Setting With a Single Resistor
- Integrated 0.6 Ohm Isolating MOSFET Switch With Inrush Current Limit
- Power Off DC-DC Input Capacitor Discharge
- 100 kHz to 500 kHz Adjustable DC-DC Switching Frequency
- DC-DC Frequency Can Be Synchronized to External Clock
- Supports Low Power Mode Operation for Higher Efficiency 50% Maximum Duty Cycle
- Soft-start Circuit to Control The Output Voltage Rise Time
- Two out-of-phase driver stages for efficient synchronous rectification or active clamp
- PoE Port Input UVLO with Programmable Threshold and Hysteresis
- Internal Differential Amplifier Simplifying Non-isolated Step Down Converter
- Over Load and Short Circuit Protection
- RoHS Compliant & Pb-Free

Applications

- IEEE802.3at and IEEE802.3af powered devices such as IP phones, WLAN Access Points and Network Cameras.
- 48V Input Telcom/Networks Hot Swappable Power Supply.

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Pin Configuration

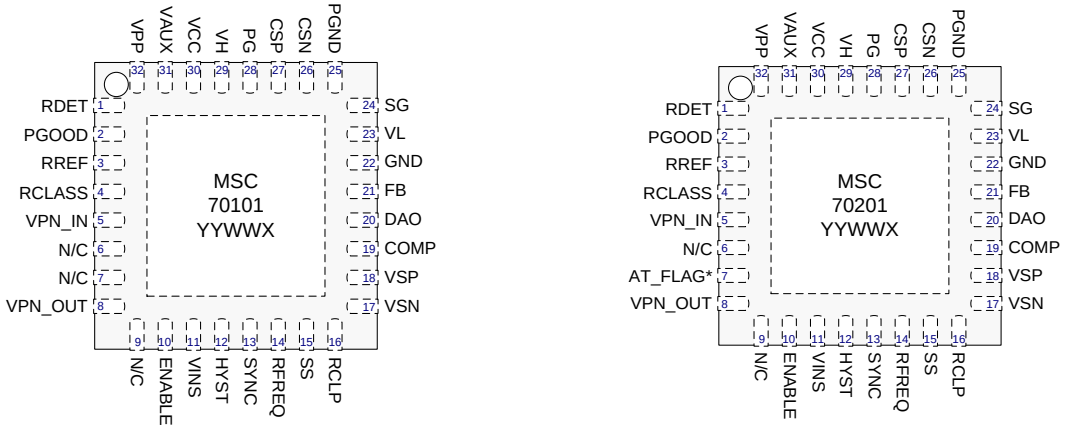

Figure 1 · Pinout QFN Package(Top View)

YYWWX = Year /Week / lot code

Ordering Information

Ambient Temperature	Type	Package	Part Number	Packaging Type
-40°C to 85°C	RoHS2 compliant, Pb-free Matte Tin Pin Finish	QFN 5x5 Plastic 32 pin	PD70101ILQ (IEEE802.3af)	Bulk / Tube
			PD70101ILQ-TR (IEEE802.3af)	Tape and Reel
			PD70201ILQ (IEEE802.3at)	Bulk / Tube
			PD70201ILQ-TR (IEEE802.3at)	Tape and Reel

Pin Description

Pin Number	PD70101 Pin Name	PD70201 Pin Name	Description
1	RDET	RDET	Valid Detection Resistor: Connect a 24.9kΩ, 1% resistor from this pin to VPP.
2	PGOOD	PGOOD	Open Drain Output (active low): This flag is generated to indicate the power rails (VPN_OUT) are ready.
3	RREF	RREF	Bias current resistor for the PD Interface. Connect a 240k 1% resistor between this pin and VPN_IN.
4	RCLASS	RCLASS	Power Classification Setting: Connect external class resistor between this pin and VPN_IN.

Pin Number	PD70101 Pin Name	PD70201 Pin Name	Description
5	VPN_IN	VPN_IN	VPort Negative Input: Connected to the isolating switch input N-channel MOSFET source.
6	N/C	N/C	Not Used.
7	N/C	AT_FLAG	Open Drain Output (active low): This flag indicates if the chip detects an IEEE 802.3at compliant PSE.
8	VPN_OUT	VPN_OUT	VPort Negative Output: Connected to the isolating switch output. N-channel MOSFET Drain.
9	N/C	N/C	Not Used.
10	ENABLE	ENABLE	Logic level Enable input for DC-DC controller. Pulling this pin to VL turns on the DC-DC controller. This allows the DC-DC controller to be turned on without power to the PD interface.
11	VINS	VINS	VPP input voltage sensing for UVLO comparator. Connect to an external resistor divider from VPP to GND. Threshold is 1.2V reference.
12	HYST	HYST	Output of the VINS/UVLO comparator. This pin is used for VPP UVLO hysteresis programming.
13	SYNC	SYNC	External Clock synchronization for the DC-DC controller. Connect an external clock as defined in the EC table to this pin to synchronize the DC-DC converter switching frequency to this clock. PG rising edge is synchronized with the clock rising edge.
14	RFREQ	RFREQ	DC-DC Switching Frequency Setting. Connect a resistor from this pin to GND to set the switching frequency.
15	SS	SS	Soft-start: Connect a capacitor from this pin to GND to set the soft-start time of the DC-DC converter. This capacitor is charged with an internal current source to 1.2V.
16	RCLP	RCLP	Low Power Mode Clamp. Connect a resistor from this pin to GND to program the LPM clampimg voltage or connect this pin to GND to disable LPM.
17	VSN	VSN	Differential Amplifier's negative input. Connect this to the junction of a resistor divider from Vo- to GND for the Direct Buck converter application.
18	VSP	VSP	Differential Amplifier's positive input. Connect this to the junction of a resistor divider from Vo+ to GND for the Direct Buck converter application.
19	COMP	COMP	Error Amplifier Output. Short to FB pin when driven directly with an optoisolator for Isolated DC-DC Converter. Connect to FB via RC compensation networks for Non-Isolated Direct Buck Converter.
20	DAO	DAO	Differential Amplifier Output. Connect to FB (externally) for Non-Isolated Direct Buck Converter.
21	FB	FB	Inverting Input of the Error Amplifier. Connect to opto-coupler for Isolated DC-DC. Connect to RC compensation networks for Non-isolated DC-DC
22	GND	GND	This is Analog GND. Connect to a local AGND plane. Soft-start capacitor and the frequency setting resistor return to this local GND plane.

Pin Number	PD70101 Pin Name	PD70201 Pin Name	Description
23	VL	VL	5V (GND reference) internal LDO Output. Connect a 1µF or higher ceramic cap from VL to GND.
24	SG	SG	Secondary Gate Driver. Output is the compliment of PG output. Leave open (NC) if not used. SG is low when in Low Power Skip Mode.
25	PGND	PGND	This is the Power Ground. Connect to a local PGND plane. Input, VCC decoupling capacitors, PG and SG drivers. Primary current sense resistor return to this PGND.
26	CSN	CSN	Negative Input of the Current Sense Amplifier. Kelvin connect to the PGND side of the primary current sense resistor.
27	CSP	CSP	Possitive Input of the Current Sense Amplifier. Kelvin connect to the Non-PGND side of the primary current sense resistor.
28	PG	PG	Primary Gate Driver. Connect to the gate of the primary side Power MOSFET, directly or via a resistor.
29	VH	VH	5V High side (VCC reference) internal LDO Output. Connect a 0.1µF or higher ceramic cap from VH to VCC.
30	VCC	VCC	Input Supply to the DC-DC Controller. Connect a 4.7µF or higher ceramic capacitor from this pin to PGND. Alternately an parallel combination of 1µF ceramic and an greater than 10µF electrolytic capacitor can be used.
31	VAUX	VAUX	Auxiliary voltage reference to VPN_OUT; this voltage can be used for DC-DC startup when operated with a bootstrapped voltage source. For applications with POE power only connect directly to VCC; for applications using multiple power sources (such as a wall adaptor), connect to VCC pin through a small, low current, 30V rated schottky diode.
32	VPP	VPP	This is the positive terminal of the POE input port. Connect to the positive terminal of the input bridges at the CDET positive side.
EP	Exposed Pad	Exposed Pad	Thermal Pad; electrically connected to VPN_IN. For proper thermal management should be tied to a large copper fill or plane that is electrically connected to VPN_IN.

Absolute Maximum Ratings

Parameter	Value	Units
VPP, RDET, VPN_OUT (with respect to VPN_IN)	-0.3V to 74	V_{DC}
RREF, RCLASS (with respect to VPN_IN)	-0.3V to 6	V
PGOOD, AT_FLAG, VAUX (with respect to VPN_OUT)	-0.3V to 74	W
VCC (with respect to PGND)	-0.3V to 40	V_{DC}
PG, SG (with respect to PGND)	-0.3V to 20	V_{DC}
VL, VSN, VSP (with respect to PGND)	-0.3V to 6	V
VH (with respect to VCC)	-0.3V to VCC - 6	V_{DC}
All Other Pins (with respect to GND)	-0.3V to VL + 0.3	V_{DC}
ESD (HBM) Protection at all I/O pins*	± 1	kV
Maximum Junction Temperature (T_{JMAX})	+150	°C
Operational Ambient Temperature	-40 to +85	°C
Storage Temperature Range	-65 to +150	°C
Peak Package Solder Reflow Temperature (40 seconds maximum exposure), MSL3	260	°C

Exceeding these ratings could cause damage to the device. All voltages are with respect to VPNIN. Currents are positive into, negative out of specified terminal. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" are not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability. *All pins except pin 2 (PGOOD) and pin 31 (VAUX). Pin 2 & 31 ESD Protection ±150V HBM.

Thermal Properties

Thermal Resistance	Typ	Units
θ_{JC} Junction to Case	5	°C/W
θ_{JP} Junction to Pad	4	
θ_{JA} Junction to Ambient	23	

Note: The θJx numbers assume no forced airflow. Junction Temperature is calculated using $T_J = T_A + (PD \times \theta J_A)$. In particular, θJ_A is a function of the PCB construction. The stated number above is for a four-layer board in accordance with JESD-51 (JEDEC) with thermal vias.

Electrical Characteristics

Symbol	Parameter	Test Conditions / Comment	PD70101 & PD70201			Units
			Min	Typ	Max	
Unless otherwise specified, the following specifications apply over the operating ambient temperature of -40°C ≤ T_A ≤ 85°C except where otherwise noted with the following test conditions: V_{PP}= 48V; V_{EN} = HIGH, f_s = 250 kHz. Production tests performed at 25°C. Unless otherwise specified V_{PP} is with respect to VPN_IN, VCC is with respect to PGND.						
PD Interface						
Power Supply						
V_{PP}	Input Voltage		0	55	57	V

Symbol	Parameter	Test Conditions / Comment	PD70101 & PD70201			Units
			Min	Typ	Max	
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Detection Mode						
DET_{RANGE}	Detection Voltage Range.	Measured between V_{PP} and VPN_{IN}	1.3		10.1	V
$RDET_{-ON}$	Detection Switch ON Resistance	2.5V ≤ (ΔV_{PP} to VPN_{IN}) ≤ 10.1V Measured between R_{DET} and VPN_{IN}			50	Ω
$R_{DET-OFF}$	Detection is Disconnected	Measured between V_{PP} and VPN_{IN}	10.1		12.8	V
$RDET_{-OFF}$	Detection switch OFF resistance	12.8V ≤ (ΔV_{PP} to VPN_{IN}) ≤ 57.0V Measured between R_{DET} and VPN_{IN}	2.0			MΩ
I_{OFFSET}	Input offset current	2.5V ≤ V_{PP} ≤ 10.1V -40°C ≤ T_J ≤ 85°C			16	µA
I_{OFFSET}		2.5V ≤ V_{PP} ≤ 10.1V -40°C ≤ T_J ≤ 55°C			10	µA
$V_{RDET-ON}$	RDET reconnection level	Measured between V_{PP} and VPN_{IN}	1.95	3.0	4.85	V
Classification Mode						
$V_{TH-LOW-ON}$	Classification Current Source, Turn ON Threshold Range Measured at V_{PP}	Turn on for any I_{CLASS} while V_{PP} increases	11.4		13.7	V
V_{HST}	Classification Disconnection Minimum Hysteresis Voltage.	Hysteresis between V_{TH}-low-on and V_{TH}-low-off		1		V
$V_{TH-HIGH-OFF}$	Classification Current Source, Turn OFF Threshold Range Measured at V_{PP}	Turn off while V_{PP} increases	20.9		23.9	V
$I_{CLASS-LIM}$	Current limit threshold		50.0	68	80.0	mA
$I_{CLASS-DIS}$	Input current I_{PP} when classification function is disabled	Class 0 RCLASS = Open			3.0	mA
I_{CLASS}-EN	Input current I_{PP} when classification function is enabled	Class 1 RCLASS = 133Ω±1%	9.50	10.5	11.5	mA
		Class 2; RCLASS = 69.8 Ω±1%	17.5	18.5	19.5	mA
		Class 3 RCLASS = 45.3 Ω±1%	26.5	28.0	29.5	mA
		Class 4 RCLASS = 30.9 Ω±1%	38.0	40.0	42.0	mA
	RCLASS Voltage		1.142		1.278	V
Mark						
V_{MARK}	Mark, working range	VPP failing edge	4.9		10.1	V
I_{MARK}	Mark Current		0.25		4	mA
Isolation Switch						
$V_{SW-START}$	Isolation Switch MOSFET switches from off to $I_{LIM-LOW}$		36		42	V

Symbol	Parameter	Test Conditions / Comment	PD70101 & PD70201			Units
			Min	Typ	Max	
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V_{SW-OFF}	Isolation Switch MOSFET switched off		30.5		34.5	V
$I_{LIM-LOW}$	Startup current limit, ILIM-LOW		130	240	330	mA
V_{DIFF}	VPN_IN to VPN_OUT Threshold voltage for $I_{LIM-LOW}$ to $I_{LIM-HIGH}$ switchover	When VPNIN to VPNOUT ≤ VDIFF, Isolating switch switches over from $I_{LIM-LOW}$ to $I_{LIM-HIGH}$.			0.7	V
OCP	Over current protection limit current		1500	1800	2000	mA
I_{LOAD}	Continuous operation load	Isolating switch at $I_{LIM-HIGH}$ PD70101			450	mA
		PD70201			1123	
$SW-RDS_{ON}$	Isolated Switch On resistance @ $I_{LIM-HIGH}$	Total resistance between VPNIN and VPNOUT Isolating switch at $I_{LIM-HIGH}$			0.6	Ω
DC/DC Capacitor Discharger						
C_{IN}	DC/DC input capacitance	For reference only Guaranteed by design (not tested in production)		220	264	µF
	Discharge current	7.0V ≤ VPP to VPNOUT ≤ 30V	22.8	32	50	mA
AT_FLAG						
	Output low voltage	I_{OL} = 0.75mA			0.4	V
		I_{OL} = 5mA			2.5	V
	Leakage current	V_{AT_FLAG} = 57V			1.7	µA
PGOOD						
	Output low voltage	I_{OL} = 0.75mA			0.4	V
		$I_{OL\ MAX}$ = 5mA			2.5	V
	Leakage current	V_{PGOOD} = 57V			1.7	µA
PD Interface Thermal Shutdown						
	Thermal Shutdown Temperature[1]		180	200	220	°C
VAUX (respect to VPN_OUT)						
$VAUX_{-OFF}$	VAUX Output Voltage Off (leakage current)	PGOOD = High impedance Load = 1MΩ			1	V
$VAUX_{-ON}$	VAUX Output Voltage On	Isolating switch at $I_{LIM-HIGH}$ and PGOOD = Low	9.8	10.5	11.8	V
I_{VAUXP}	Output Current Peak	Capacitor = 30µF When T_{LOAD} ≤ 5mS Isolating switch at $I_{LIM-HIGH}$ and PGOOD = Low	0		10	mA
I_{VAUXC}	Output Continuous Current	When T_{LOAD} ≤10mS Isolating switch at $I_{LIM-HIGH}$ and PGOOD = Low	0		2	mA

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Symbol	Parameter	Test Conditions / Comment	PD70101 & PD70201			Units
			Min	Typ	Max	
Unless otherwise specified, the following specifications apply over the operating ambient temperature of -40°C ≤ T_A ≤ 85°C except where otherwise noted with the following test conditions: V_{PP}= 48V; V_{EN} = HIGH, f_s = 250 kHz. Production tests performed at 25°C. Unless otherwise specified V_{PP} is with respect to VPN_IN, VCC is with respect to PGND.						
I_{VAUX}	VAUX Output Current Limit	Isolating switch at $I_{LIM-HIGH}$ and PGOOD = Low	10		32	mA
DC-DC Controller						
VCC						
VCC	Maximum Input Operating Voltage				20	V
I_{VCC}	Input Current	VCC< VCC_UVLO or ENABLE = Low. See Note 5		250	2000	µA
		V_{ENABLE} and VINS = High; V_{VCC} < VCC_UVLO_UP; -40°C ≤ Temp ≤ +55°C. See Note 5			4.5	mA
		VCC >VCC_UVLO & ENABLE = High, No Load on PG, SG, VL, and FSW = 500kHz.			3	mA
VCC_UVLO	VCC UVLO Rising Threshold	VCC raising edge	8.85	9.15	9.5	V
VCC_UVLO	VCC UVLO Falling Threshold	VCC falling edge	7	7.3	7.6	V
POE Port Input UVLO						
VINS	UVLO Threshold		1.171	1.200	1.229	V
	VINS Input Current		-0.1		+0.1	µA
HYST-V_{OH}	HYST Output High Voltage	I_{SOURCE} = 1mA	2.8			V
HYST-V_{OL}	HYST Output Low Voltage	I_{SINK} = 3mA			0.4	V
Internal LDO's						
VL	+5V LDO	I_L < 5mA	4.75	5	5.25	V
VH	-5V LDO	Reference to VCC		-5		V
Soft-Start						
I_{SS_CHG}	Soft-start Charging Current[2]	R_{FREQ} = 33.2kΩ; $V_{SOFTSTART}$ = 0.5V	32	36	40	µA
I_{SS_DIS}	Soft-start Discharging Current	$V_{SOFTSTART}$ = 0.5V; % of I_{SS_CHG}		10		%
V_{SS_CH}	Soft-start Completion Threshold[1]	% of 1.2V	90		95	%
V_{SS_DISCH}	Soft-start Discharge Completion Threshold[1]			50		mV
R_{SS_DISCH}	Soft-start Discharge FET On Resistance			50		Ω
t_{DISCH}	Soft-start Discharge FET On Time[1]	1 cyc = 1/F_{FREQ}		32		cyc
Switching Frequency and Synchronization						
F_{FREQ}	Switching Frequency Range		100		500	kHz
F_{FREQ}	Switching Frequency Accuracy[3]	R_{FREQ} = 33.2k	285	315	345	kHz
F_{SYNC}	Synchronization Frequency Range	F_{SYNC} > 2x F_{FREQ}	200		1000	kHz
$V_{SYNC-HIGH}$	Synchronization Voltage High Threshold		2.4		5	V
$V_{SYNC-LOW}$	Synchronization Voltage Low Threshold				0.8	V

Symbol	Parameter	Test Conditions / Comment	PD70101 & PD70201			Units
			Min	Typ	Max	
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PW_{SYNC_MIN}	Synchronization Minimum Pulse Width		100			ns
PW_{SYNC_MAX}	Synchronization Maximum PWM Duty				90	%
I_{SYNC}	Synchronization Input Current		-1.3		+1.3	µA
Error Amplifier						
$Gain_{DC_OPL}$	DC Open Loop Gain[1]	R_{LOAD} = 100k	70	100		dB
AV_{UGBW}	Unity Gain Bandwidth[1]	C_{LOAD} = 10pF	2	5		MHz
I_{COMP_OUT}	Output Sourcing Current	0.2V ≤ V_{COMP} ≤ 1.3V	110		620	µA
I_{COMP_IN}	Output Sink Current	0.2V ≤ V_{COMP} ≤ 1.3V	145		495	µA
V_{EA_CMR}	Input Common Mode Range		0		2	V
V_{FB}	Feedback Voltage	COMP shorted to FB	1.171	1.200	1.229	V
I_{FB}	FB Pin Input Current		-50		50	nA
V_{COMP}	Output Clamp Voltage		1.8	2.1	2.6	V
PWM Comparator						
V_{RCLP}	RCLP Voltage Range		0		1	V
Low Power Mode (Skip Pulse Mode)						
	Low Power Skip Mode Threshold[1,4]	V_{COMP} Rising (% of V_{RCLP})		95		%
		V_{COMP} Falling (% of V_{RCLP})		90		%
Current Sense Amplifier and Current Limit						
$Gain_{CSA}$	Gain	Measure at DC	4.75	5.0	5.25	V/V
V_{CSA_CMR}	Input Common Mode Range		0		2.0	V
	Output Rise/Fall time[1]	10% to 90%			75	ns
t_{BLANK}	Blanking Time[1]		50		100	ns
V_{ILIM_TH}	Current Limit Threshold		1.1	1.2	1.3	V
V_{IMAX_TH}	Current Max Threshold		1.7	1.8	1.9	v
Differential Amplifier						
$Gain_{DA}$	Gain	Measured at DC	6.86	7.0	7.14	V/V
AV_{UGBW_DA}	Unity Gain Bandwidth[1]			5		MHz
V_{DA_CMR}	Common Mode Range		0		3.5	V
	Input Offset Voltage		-7		+7	mV
	Input Bias Current		-1		+1	µA
Output Drivers						
PG Rds_{ONH}	Primary Gate (PG) High On Resistance			10		Ω
PG Rds_{ONL}	Primary Gate (PG) Low On Resistance			5		Ω
SG Rds_{ONH}	Secondary Gate (SG) High On Resistance			10		Ω
SG Rds_{ONL}	Secondary Gate (SG) Low On Resistance			10		Ω

Symbol	Parameter	Test Conditions / Comment	PD70101 & PD70201			Units
			Min	Typ	Max	
Unless otherwise specified, the following specifications apply over the operating ambient temperature of -40°C ≤ T_A ≤ 85°C except where otherwise noted with the following test conditions: V_{PP}= 48V; V_{EN} = HIGH, f_s = 250 kHz. Production tests performed at 25°C. Unless otherwise specified V_{PP} is with respect to VPN_IN, VCC is with respect to PGND.						
T_{DEAD}	Dead Time – PG low to SG high or SG low to PG high	C_{LOAD} on PG and SG = 1000pF		110		ns
	PG Minimum On Time				120	ns
	PG Maximum Duty Cycle		44.5		50	%
Logic (ENABLE Pin)						
V_{HI}	Logic High Threshold		2.0			V
V_{LO}	Logic Low Threshold				0.8	V
	Input Current		-1		1	µA
PWM Controller Thermal Shutdown						
T_{SD}	Thermal Shutdown Threshold[1]			157		°C
T_{HYST}	Threshold Hysteresis[1]			15	30	

Notes:

1) Guaranteed by design
2) Soft Start Charge Current Equation: I_{ss_chg} = 1.2V/R_{FREQ}
3) Switching Frequency Equation:

$$Freq = \frac{1}{(90pF \times R_{FREQ}) + 150ns}$$ where Freq is [Hz]

4) Low Power Mode Clamp Equation: V_{CLAMP} = 0.3 * (R_{RCLP}/R_{FREQ})
5) Min and Maximum current are guaranteed by design.

Functional Block Diagram

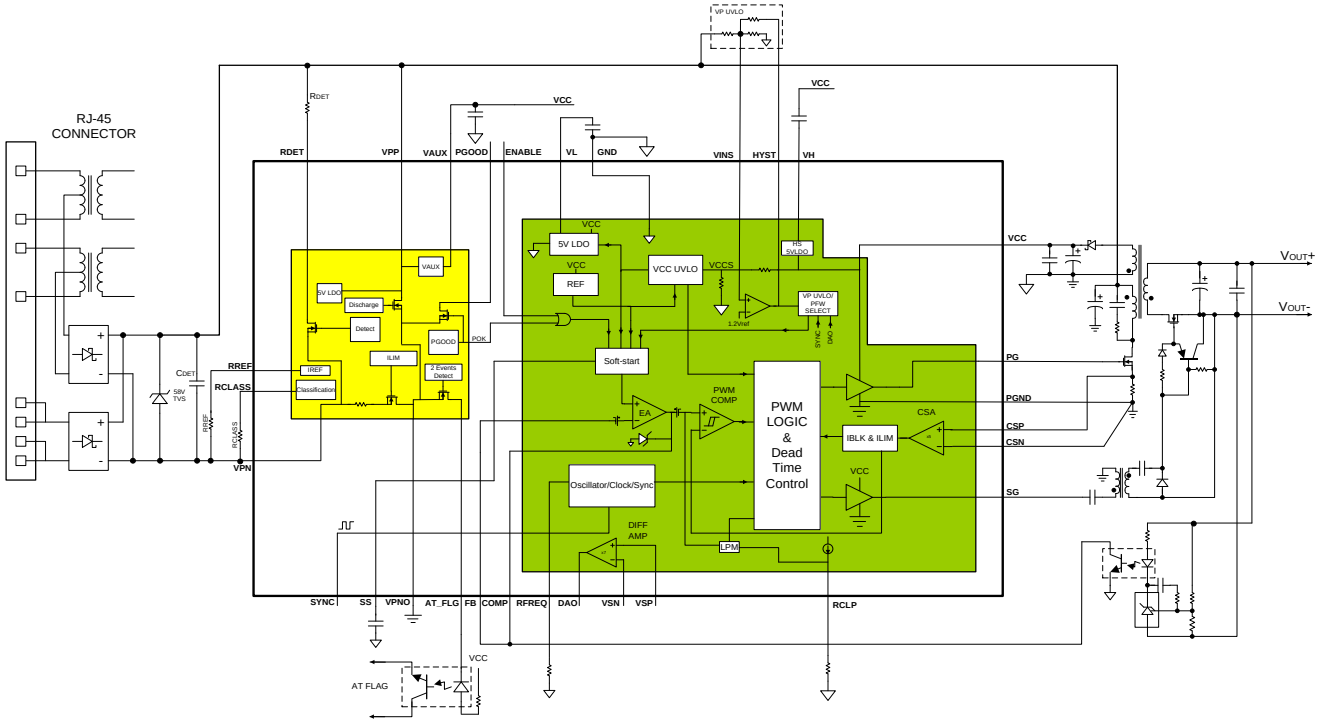

Figure 2 · PD70101/PD70201 Functional Block Diagram (PD70201 shown)

Typical Applications

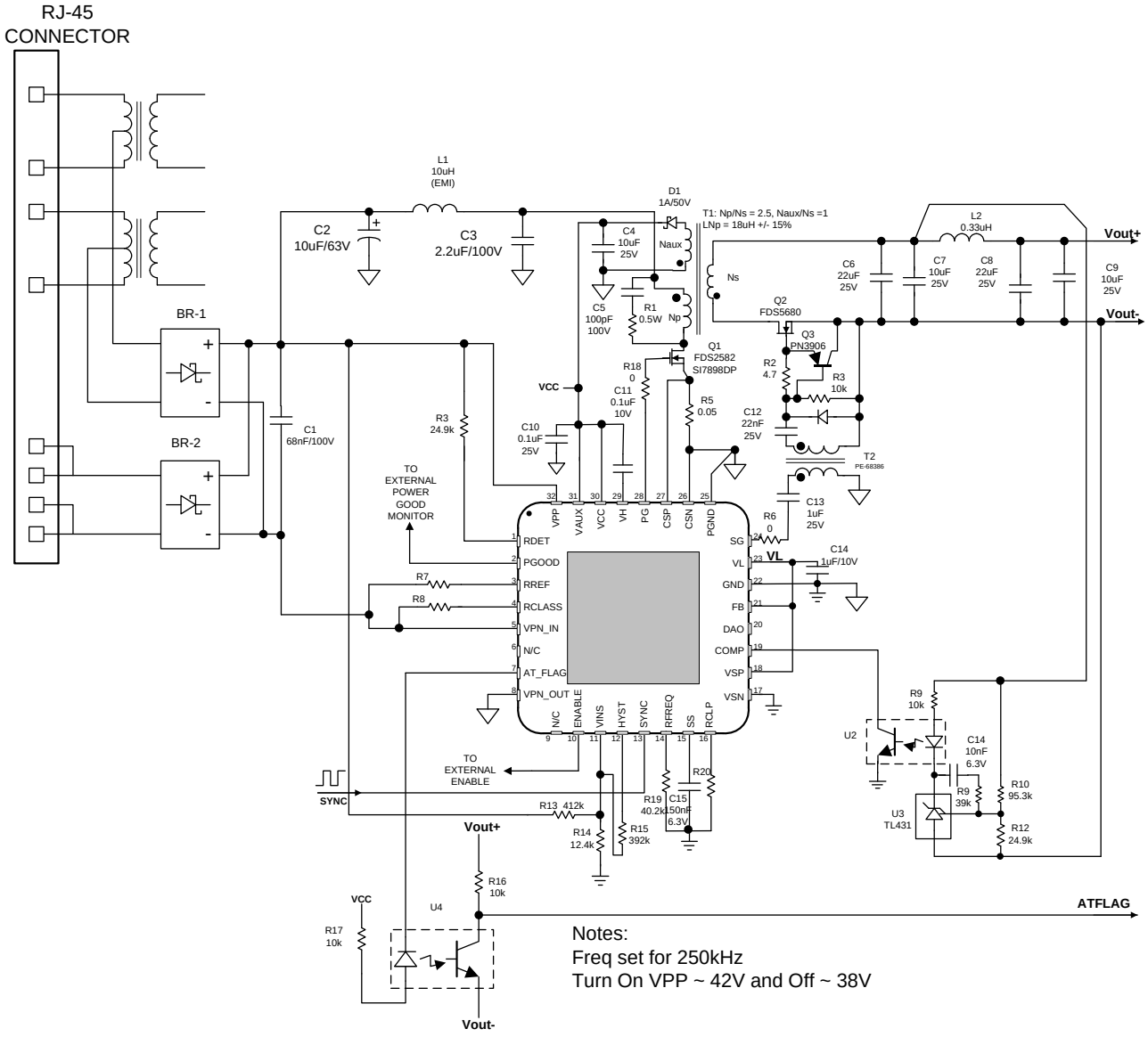

Figure 3 · 12V2A Output Isolated Fly-back with Secondary Synchronous Rectification

Typical Applications

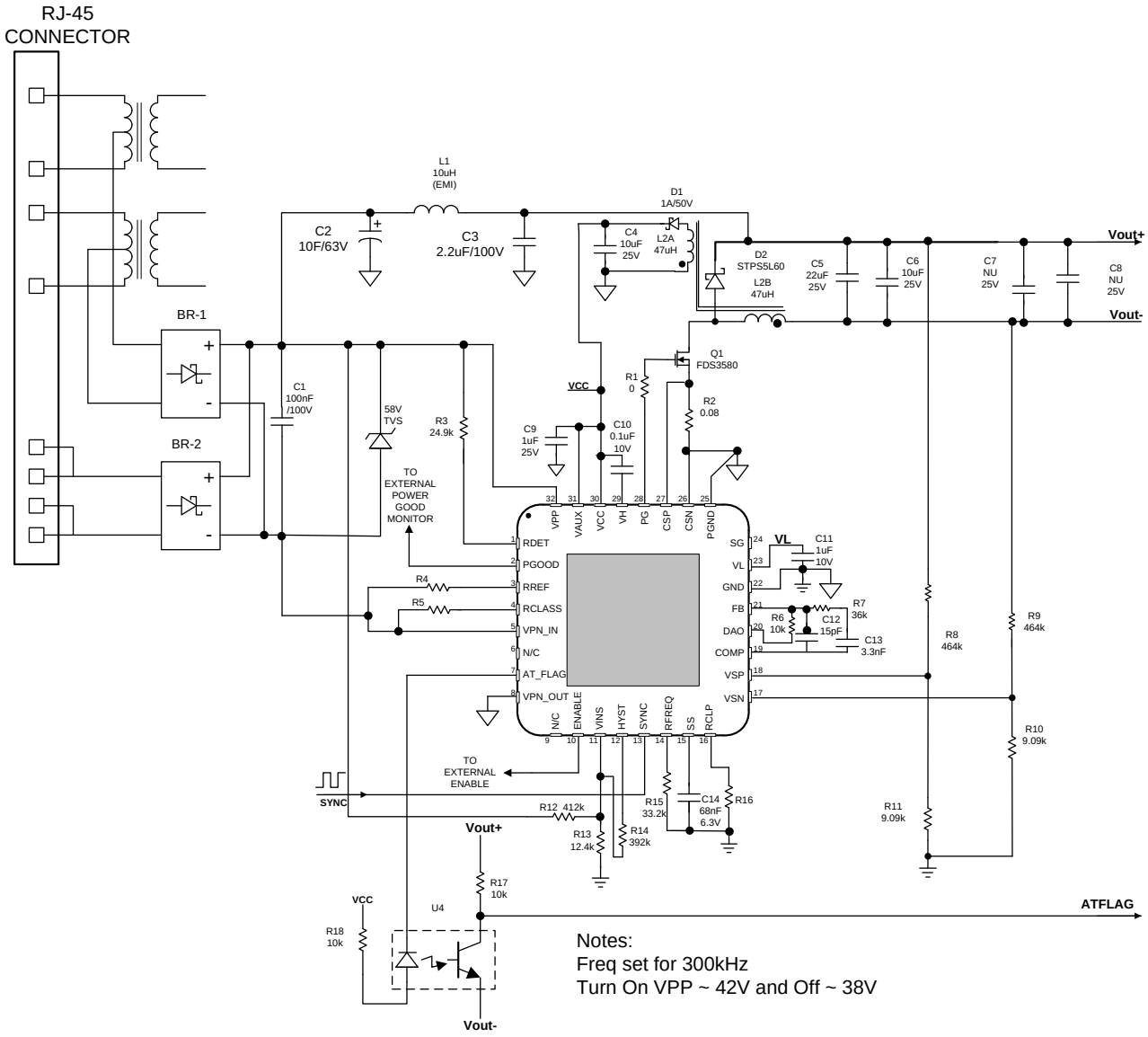

Figure 4 · 12V2.1A Output Non-Isolated Direct Buck Application

Theory of Operation

General Description

PD70101/PD70201 IC integrates IEEE 802.3af/at compliant PD Front-End functions including Detection, Physical Layer Classification, Two-Events Classification (PD70201 only), Power Good, Soft Start Current Limiting, Over-Current Protection, and Bulk Capacitor Discharge with a PWM controller. The integrated PWM controller function provides a PWM controller solution with a minimum requirement of external components.

Detection

IEEE 802.3af/at compliant detection is provided by means of a 24.9KΩ resistor connected between VPP and RDET pin. RDET pin is connected to VPN_IN via an open drain MOSFET with a maximum specified RDSON of 50Ω. Internal logic monitors VPP to VPN_IN and connects the RDET pin to VPN_IN when the rising VPP to VPN_IN voltage is between 1.1V and 10.1V. When rising VPP to VPN_IN voltages exceed 10.1V, the MOSFET is switched off. Once above 10.1V, falling VPP to VPN_IN voltage between 2.45V and 4.85V will reconnect RDET pin to VPN_IN.

Physical Layer Classification

Physical Layer (hardware) Classification per IEEE 802.3af/at is generated via a regulated reference voltage of 1.2V, switched onto the RCLASS pin. Internal logic monitors the VPP to VPN_IN voltage and connects the 1.2V reference to RCLASS pin at a rising VPP to VPN_IN voltage threshold between 11.4V and 13.7V. Once VPP to VPN_IN has exceeded the rising threshold, there is a 1V typical hysteresis between the VPP rising (turn-on) threshold and the VPP falling (turn-off) threshold.

The 1.2V reference stays connected to the RCLASS pin until the VPP to VPN_IN rising voltage exceeds the upper turn-off threshold of 20.9V to 23.9V. The 1.2V reference voltage is disconnected from the RCLASS pin at VPP to VPN_IN voltages above the upper threshold.

Classification current signature is provided via a resistor connected between RCLASS pin and VPN_IN. The classification current is therefore the current drawn by the PD70101/PD70201 IC during the classification phase, and is simply the 1.2V reference voltage divided by the RCLASS resistor value. The maximum current available at the RCLASS pin is current limited to 68mA (typical).

Two-Events Detection and AT Flag

The PD70201 IC provides IEEE 802.3at Type 2 compliant detection of the “Two Events Classification Signature”, and generation of the AT flag. This feature is available on the PD70201 IC only.

Simply put, the “Two Events Classification Signature” is a mean by which an IEEE 802.3at Type 2 Power Source can inform a compliant Power Device (PD) that it is AT Type 2 compliant, and as such is capable of providing AT Type 2 power levels.

The Power Source communicates the Type 2 compliant signature by toggling the VPP to VPN_IN voltage twice (2 “events”) during the Physical Layer Classification phase. The VPP to VPN_IN voltage is toggled from the Physical Layer Classification’s voltage level (13.5V to 20.9V) down to a voltage “Mark” level. Voltage “Mark” level is specified as a VPP to VPN_IN voltage of 4.9V to 10.1V.

PD70201 IC recognizes a VPP to VPN_IN falling edge from Classification level to Mark level as being one event of the Two-Events Signature. If two such falling edges are detected, PD70201 will assert AT flag by means of an open drain MOSFET connected between AT_FLAG pin and VPN_OUT.

AT_FLAG pin is active low; a low impedance state between AT_FLAG and VPN_OUT indicates a valid Two-Events Classification Signature was received, and the Power Source is AT Type 2 compliant.

AT_FLAG MOSFET is capable of 5mA of current and can be pulled up to VPP.

Soft Start and Inrush Current Protection

PD70101/PD70201 IC contains an internal isolation switch that provides ground isolation between Power Source and PD application during Detection and Classification phases. The isolation switch is a N-channel MOSFET, wired in a

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common source configuration where the MOSFET's Source is connected to Power Source ground at VPN_IN, and the MOSFET's Drain is connected to application's primary ground at VPN_OUT

Internal logic monitors VPP to VPN_IN voltage and keeps the MOSFET in a high impedance state until VPP to VPN_IN voltage reaches turn-on threshold of 36V to 42V. Once VPP to VPN_IN voltage exceeds this threshold, the MOSFET is switched into one of two modes.

Mode into which the MOSFET is switched is determined by the voltage developed across the MOSFET, or put another way, the VPN_OUT to VPN_IN differential voltage. Two modes are defined below:

Isolation Switch Modes		
VPN_OUT to VPN_IN	**Mode**	**Description**
≥ 0.7V	Soft Start Mode	Limits VPN_OUT current to 240mA (typical)
≤ 0.7V	Normal Operating Mode	Limits VPN_OUT current to 1.8A (typical)

By controlling the MOSFET current based on VPN_OUT to VPN_IN voltage, inrush currents generated by fully discharged bulk capacitors can be limited. This method limits current to a maximum of 350mA, compliant with IEEE 802.3af/at specification.

Soft Start current limiting is required to reduce occurrences of voltage sag at the PD input during device power-up. A comparison is shown in Figure 3.

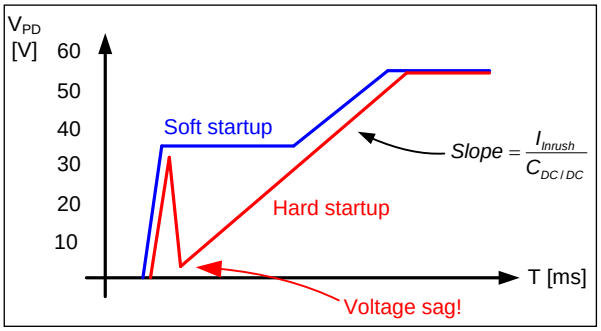

Figure 5 · Comparison of input voltages without Soft-start (hard startup), and Soft-start (soft startup)

Once bulk capacitance has charged up to a point where VPN_OUT to VPN_IN differential voltage is less than 0.7V, the isolation MOSFET is switched into normal operating mode with MOSFET current limit set at 1.8A (typical), to provide overcurrent protection.

PD70101 and PD70201 ICs are different in their respective isolation MOSFET's continuous current handling capability:

PD70101: 450mA (max.)

PD70201: 1123mA (max.)

An adequate heatsink for the PD70101/PD70201 IC's exposed pad must be provided to achieve these current levels without damaging the IC. A large, heavy copper fill area and/or a heavy ground plane with Thermal Vias are recommended.

Internal logic monitoring VPP to VPN_IN will place the isolation switch MOSFET in a high impedance state if voltage between VPP and VPN_IN drops below 31V to 34V.

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Over- Current Protection

An over-current protection is provided on the PD70101/PD70201 IC using the Isolation Switch MOSFET, which limits the VPN_OUT current to 1.8A during normal operation. See previous description of Soft-start.

Power Good

During Soft Start mode, the PD70101/PD70201 IC monitors VPN_OUT to VPN_IN differential voltage. When this voltage is less than 0.7V (max.), the IC enters normal operation mode and the isolation switch current limit is increased to 1.8A (typical). At this same 0.7V (max.) threshold the Power Good signal is asserted by means of an open drain MOSFET between PGOOD and VPN_OUT.

PGOOD pin is active low; a low impedance state between PGOOD and VPN_OUT indicates the Soft Start mode has finished and the isolation switch has transitioned into normal operating mode.

PGOOD MOSFET can handle current of 5mA and can be pulled up to VPP.

The application load should begin after no less than 80msec after PGOOD is activated.

Start-up Supply

PD70101/PD70201 IC provides a 10.5V (typical) regulated output used as a start-up supply for the integrated DC/DC controller when VCC is provided via a bootstrap winding. This regulated supply is available at VAUX pin, and is referenced to VPN_OUT pin. The VAUX start-up supply is current-limited at 10mA (min.).

For stability, the start-up regulator requires a minimum of 4.7µF ceramic capacitor connected directly between VAUX and PGND pins (most applications will connect PGND to VPN_OUT).

For applications where power to the DC-DC controller is provided by POE only, the VAUX pin is connected directly to VCC. For applications which have alternate power sources (such as a wall adaptor), the VAUX pin output is connected to the VCC pin through a series diode. This diode is typically a low current diode with a 30V rating.

PD Interface Thermal Protection

Both PD70101 and PD70201 IC contain temperature sensors which individually monitor both the isolation MOSFET and the Classification Current Source for over temperature conditions. In case of an over temperature condition, the sensor will activate protection circuitry which will disconnect its respective monitored function.

Bulk Capacitor Discharge

The bulk capacitor discharge circuitry eliminates the need to place a diode in series with the VPP line to prevent an application's bulk capacitance from discharging through the detection resistor and the isolation switch MOSFET's body diode. Discharge current through the detection resistor can cause failure of the detection signature in cases where a PD is connected and the bulk capacitance is not fully discharged.

During normal operation, PD70101/PD70201 IC continuously monitors voltage at VPP to VPN_IN. Should VPP to VPN_IN voltage fall below isolation switch turn-off threshold (31V to 34V), isolation switch MOSFET is immediately placed in a high-impedance state. At this point the internal logic monitors the voltage at VPP to VPN_OUT.

If VPP to VPN_OUT voltage is between 1.5V to 32V, a 23mA (min.) constant current source is connected across the VPP and VPN_OUT pins. This constant current source provides bulk capacitor discharge.

A 220µF bulk capacitance can be discharged from 32V to 1.5V in a maximum period of 292ms.

DC-DC Start-up

The DC-DC controller starts up when it receives the PGOOD high signal from the Front End, or ENABLE goes high provided that VCC UVLO have passed. When the PGOOD signal or ENABLE goes high, the start-up sequence begins with ramping up the SS pin from GND to 1.2V. For isolated applications the output voltage may reach the maximum level before the SS reaches 1.2V, depending on the output loading condition. In applications with lighter loads, the output reaches regulation level sooner than in heavy loads, as in this mode the SS voltage directly controls the peak inductor current; hence the energy is delivered to the load. The external secondary error amplifier regulates the output voltage and controls the peak inductor current via the opto-coupler across the isolation barrier.

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For non-isolated applications, because the internal error amplifier is used to close the regulation loop, the output reaches the regulation level when SS reaches 1.2V.

An additional internal offset is added to the FB to ensure that COMP does not reach its upper limit because of amplifier input offset. This offset is removed (slowly to avoid overshoot) when the SS ramp is complete.

Low Power Mode is not supported during SS ramp as it is not necessary.

Current Limit and Short Circuit Protection

The DC-DC converter is a peak current mode controller; an internal current sense amplifier with a gain of 5 monitors the voltage across an external current sense resistor and regulates the output based on the current through the resistor. If the output of the internal current sense amplifier reaches 1.2V, the converter will truncated the PWM output, and thus limit the output current.

If the output of the internal current sense amplifier reaches 1.8V, the controller enters hiccup mode by discharging the SS capacitor with a constant current that equals 10% of the charging current during ramp up.

This discharge continues until VSS = 50 mV where an internal ~50Ω MOSFET connected to SS turns on for 25 clock cycles to ensure the SS capacitor fully discharges to GND before ramping back up and restart. The converter will exit the hiccup mode when the over current condition is removed.

Low Power Mode Operation

The devices offer a pulse skipping operation for light load condition, referred as Low Power Mode (LPM), to improve the efficiency of light load operation by reducing the power dissipation especially in high frequency switching. Using an external resistor from RCLP pin to GND, the user can program the output power when the unit enters pulse skipping.

Pulse skipping mode is disabled until SS ramp is completed, regardless of the LPM status.

Input (VPP & VCC) Under Voltage Lock Out

The PD interface circuit offers an internal PGOOD signal that can be used to start the DC-DC converter; however the threshold of the PGOOD is fixed at VPN_OUT-VPN_IN ≤ 0.7V. This may not fit all possible applications. Therefore the device offers an option to have a programmable UVLO which is tied to level of VPP-VPN_OUT, plus a programmable hysteresis. The voltage developed across a simple resistor divider is sensed at VINS, and will enable/disable the PWM controller at a nominal 1.2V threshold. A third resistor connected between VINS and HYST pins allows programmable hysteresis. This feature enables the end user to tailor to any desired systems application's requirement for turn on and turn off time. In addition to the VPP sensing for UVLO, the devices also have VCC UVLO to ensure that the PWM controller is always properly powered during operation. These features provide robust solutions under various systems disturbances.

External Enable

The PD interface circuit provides an internal PGOOD signal that is used to enable the DC-DC converter when powered by the POE input; however for applications that require input power from a wall adaptor, the internal PGOOD signal is not functional. For these applications an external enable input is provided, allowing a non-POE power source (such as a wall adaptor) the ability to start the DC-DC converter. The Enable pin is active high, and is driven by a 5V maximum signal referenced to GND. When the DC-DC converter is powered by the PD interface (POE power), the Enable pin will not disable the controller. It may be tied to ground or left floating when not used.

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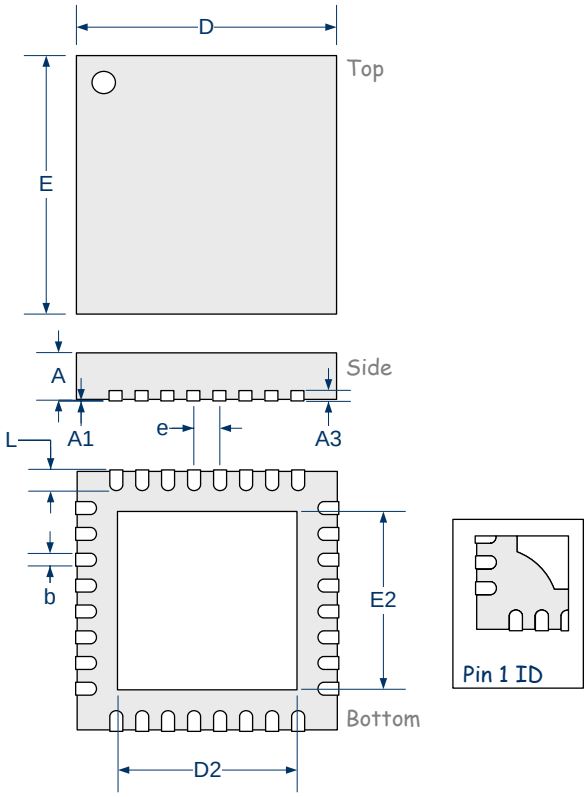
Package Outline Dimensions

The package is halogen free and meets RoHS2 and REACH standards.



Dim	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.031	0.039
A1	0	0.05	0	0.002
A3	0.20 REF		0.008 REF	
b	0.18	0.30	0.007	0.012
D	5.00 BSC		0.197 BSC	
D2	3.30	3.60	0.130	0.142
E	5.00 BSC		0.197 BSC	
E2	3.30	3.60	0.130	0.142
e	0.50 BSC		0.02 BSC	
L	0.30	0.50	0.012	0.020

Note:

1. Dimensions do not include protrusions; these shall not exceed 0.155mm (.006”) on any side. Lead dimension shall not include solder coverage.
2. Dimensions are in mm, inches are for reference only.

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Revision History

Revision Level / Date	Para. Affected	Description
1.0 Sep 25 2011		Production Data Sheet release
1.1 Feb 2012		Updated Document Formatting and Updated Address Footer
1.2 Jun 25 2012		Update Switching Frequency Accuracy spec limits and equation in note 3.
1.3 Nov 21 2013		Update IVcc disable, add note 5 and remove A from 70101A from the package pin out.
1.4 Feb 13 2014		General update
1.5 Feb 20 2014		TYPOs Fixes
1.6 Mar 20 2014		Update diff amp gain at Figure 2
1.7 Nov 13 2014		Update continuous operation load current parameter on page 6 Update Pin 3 description on page 2
1.8 May 18 2015		Update diff amp and GND connection at Figure 2 and 3. Add the diff amp input (VSN, VSP) to Absolute Maximum Ratings table
1.9 November 2015		Added maximum value for $V_{SW-START}$
2.0 January 2017		Changed MSL from 1 to 3, updated formatting and disclaimer

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